TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74HCT08AP,TC74HCT08AF,TC74HCT08AFN

### Quad 2-Input AND Gate

The TC74HCT08A is a high speed CMOS 2-INPUT AND GATE fabricated with silicon gate C<sup>2</sup>MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

This device may be used as a level converter for interfacing TTL or NMOS to High Speed CMOS. The inputs are compatible with TTL, NMOS and CMOS output voltage levels.

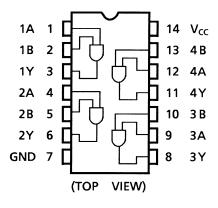
The internal circuit is composed of 4-stages including buffer output, which provide high noise immunity and stable output.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

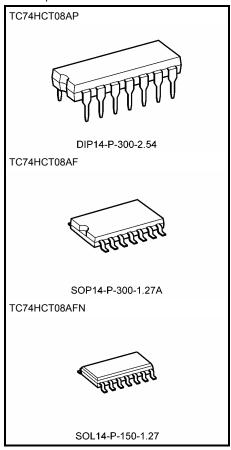
#### **Features**

- High speed:  $t_{pd} = 10 \text{ ns (typ.)}$  at  $V_{CC} = 5 \text{ V}$
- Low power dissipation:  $I_{CC} = 1 \mu A \text{ (max)}$  at  $T_{a} = 25 \text{°C}$
- Compatible with TTL outputs:  $V_{IH} = 2 V (min)$  $V_{IL} = 0.8 V (max)$
- Wide interfacing ability: LSTTL, NMOS, CMOS
- Output drive capability: 10 LSTTL loads
- Symmetrical output impedance: |IOH| = IOL = 4 mA (min)
- Balanced propagation delays:  $t_{pLH} \simeq t_{pHL}$
- Pin and function compatible with 74LS08

#### **Pin Assignment**



Note: xxxFN (JEDEC SOP) is not available in Japan.



Weight

DIP14-P-300-2.54 : 0.96 g (typ.) SOP14-P-300-1.27A : 0.18 g (typ.) SOL14-P-150-1.27 : 0.12 g (typ.)

2007-10-01

#### **IEC Logic Symbol**

		_
1A (1)	&	(3) 1Y
2A (4)		(6) 2Y
2B (9)		(8) 3Y
3B (10) 4A (12)		(11)
4B (13)		4Y

#### **Truth Table**

Α	В	Υ
L	L	L
L	Н	L
Н	L	L
Н	Н	Н

#### **Absolute Maximum Ratings (Note 1)**

Characteristics	Symbol	Rating	Unit
Supply voltage range	V <sub>CC</sub>	−0.5~7	V
DC input voltage	VIN	-0.5~V <sub>CC</sub> + 0.5	V
DC output voltage	V <sub>OUT</sub>	-0.5~V <sub>CC</sub> + 0.5	V
Input diode current	lıĸ	±20	mA
Output diode current	lok	±20	mA
DC output current	Гоит	±25	mA
DC V <sub>CC</sub> /ground current	Icc	±50	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T <sub>stg</sub>	-65~150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta =  $-40 \text{ to } 65^{\circ}\text{C}$ . From Ta =  $65 \text{ to } 85^{\circ}\text{C}$  a derating factor of  $-10 \text{ mW}/^{\circ}\text{C}$  shall be applied until 300 mW

2

#### **Operating Ranges (Note)**

Characteristics	Symbol	Rating	Unit
Supply voltage	V <sub>CC</sub>	4.5~5.5	V
Input voltage	V <sub>IN</sub>	0~V <sub>CC</sub>	V
Output voltage	Vout	0~V <sub>CC</sub>	V
Operating temperature	T <sub>opr</sub>	-40~85	°C
Input rise and fall time	t <sub>r</sub> , t <sub>f</sub>	0~500	ns

Note: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.



#### **Electrical Characteristics**

#### **DC Characteristics**

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40~85°C		Unit	
Characteristics	Symbol				Min	Тур.	Max	Min	Max	Offic
High-level input voltage	V <sub>IH</sub>	_		4.5~5.5	2.0	_	_	2.0		٧
Low-level input voltage	V <sub>IL</sub>	_		4.5~5.5	_	_	0.8	_	0.8	٧
High-level output	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	$I_{OH} = -20 \ \mu A$	4.5	4.4	4.5	_	4.4	_	V
voltage			I <sub>OH</sub> = -4 mA	4.5	4.18	4.31	_	4.13	_	v
Low-level output	V <sub>OL</sub>	VIN	$I_{OL} = 20 \ \mu A$	4.5	_	0.0	0.1	_	0.1	V
voltage		$= V_{IH}$ or $V_{IL}$	I <sub>OL</sub> = 4 mA	4.5	_	0.17	0.26	_	0.33	V
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	_	±0.1	_	±1.0	μА
Icc		V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	_	1.0	_	10.0	μА
Quiescent supply current	IC	Per input: $V_{IN} = 0.5 \text{ V or } 2.4 \text{ V}$ Other input: $V_{CC}$ or GND		5.5	_	_	2.0	_	2.9	mA

#### AC Characteristics ( $C_L = 15 \text{ pF}$ , $V_{CC} = 5 \text{ V}$ , $Ta = 25^{\circ}\text{C}$ , input: $t_r = t_f = 6 \text{ ns}$ )

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Output transition time	t <sub>TLH</sub>	_	_	6	12	ns
Propagation delay time	t <sub>pLH</sub>			10	16	ns

#### AC Characteristics ( $C_L = 50$ pF, input: $t_r = t_f = 6$ ns)

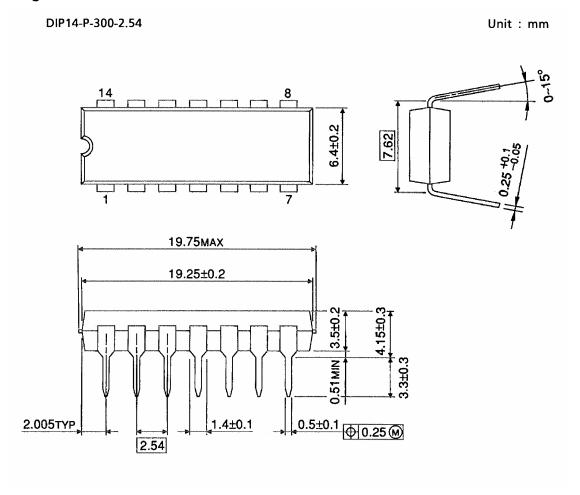
Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40~85°C		- Unit
Characteristics	Syllibol		V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Offic
Output transition time	t <sub>TLH</sub>		4.5	_	8	15	_	19	20
Output transition time	$t_{THL}$	_	5.5	_	7	13	_	16	ns
Propagation delay time	t <sub>pLH</sub>		4.5	_	13	20	_	25	no
	t <sub>pHL</sub>		5.5	_	11	18	_	23	ns
Input capacitance	C <sub>IN</sub>			_	5	10	_	10	pF
Power dissipation capacitance	C <sub>PD</sub>				24				ηE
	(Note)	_		_	24		_		pF

Note: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC}$  (opr) =  $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4$  (per gate)

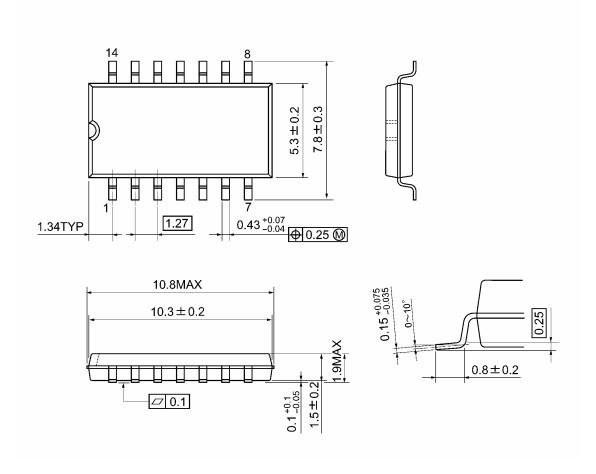
## **Package Dimensions**



Weight: 0.96 g (typ.)

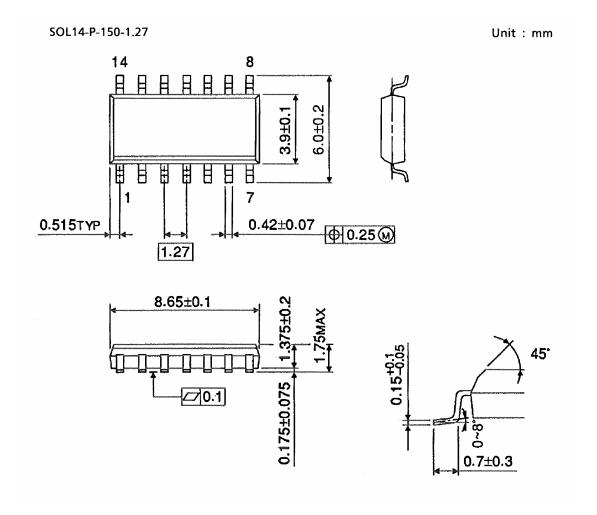
## **Package Dimensions**

SOP14-P-300-1.27A Unit: mm



Weight: 0.18 g (typ.)

## **Package Dimensions (Note)**



Note: This package is not available in Japan.

Weight: 0.12 g (typ.)

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20070701-EN GENERAL

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